A rst-principles study of wurtzite-structure M nO

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A bstract

We present results of a density functional theory study of M nO in the wurtzite structure. O urm otivation is provided by recent experim ents reporting ferrom agnetism in M n-doped wurtzite-structure ZnO.We nd that wurtzite M nO a) is not strongly energetically disfavored com pared with the ground state rocksalt M nO, b) shows strong m agneto-structural coupling and c) has a piezoelectric response that is larger than that of ZnO. These predictions augur well for the creation of ferrom agnetic piezoelectric sem iconductors based on M n-doped ZnO.

1 Introduction

The wurtzite structure adopted by ZnO does not have a center of inversion symmetry and therefore permits the occurrence of piezoelectricity. Indeed previous studies have revealed that the ZnO piezoelectric coe cients are substantial [1] because of incom plete cancellation between opposing ionic and electronic contributions [2, 3]. ZnO is already widely used in variators for surge protection and as liters for incoming television signals. The large piezoelectric response m ight provide in proved electronic device performance, for example, enhanced and tunable optical devices and optical wave resonators.

A dditional interest in ZnO-based systems has recently been stimulated by predictions of ferrom agnetism in transition m etal-doped ZnO using a simple mean eld model [4] and also by density functionalm ethods [5, 6]. Num erous experim ental reports of ferrom agnetism [7, 8, 9, 10, 11] including some above room temperature [12] have also appeared. A lthough m ore recent experim ental [13] and theoretical [14] studies call these earlier observations into question, there is a clear need for further research in this eld.

In this paper we investigate the fundam ental question of what happens to the piezoelectric response when M n is substituted for Zn in the wurtzite structure. The answer is not obvious; som e wurtzite materials, such as BeO, do not show a large piezoelectric response even though it is allowed by the non-centrosymm etricity of the crystal structure. The situation is even more complicated in the case of transition-metal substituents because of the availability of partially- lled 3d states which can become e involved in chemical bonding. Such states have been shown to strongly suppress the occurrence of ferroelectricity [15], but their in uence on piezoelectricity has not been previously investigated. We choose M n as our model transition metal dopant because the 3d band of the M n²⁺ ion is exactly half-lled, with a gap between the up-spin occupied states and empty down-spin states. Therefore we anticipate a more straightforward band structure than in the case of other transition m etals in which one of the bands is usually partially led. A loo, such an arrangem ent is more likely to result in an insulating state, which is a prerequisite for the occurrence of piezoelectricity.

O urprim ary nding is that wurtzite M nO in fact has a larger piezoelectric response than ZnO by upto around 3 times. This remarkable result suggests that, in addition to being ferrom agnetic, transition m etal doped ZnO should have a strong piezoelectric response. D evice applications that have been suggested for such m agnetic piezoelectrics, include variable transducers with m agnetically-tunable piezoelectricity, and electric eld or stress-controlled ferrom agnetic resonance devices [16]. A lso, the ability to couple with either the m agnetic or the electric polarization will o er an extra degree of freedom in the design of conventional sensors, actuators, transducers and storage devices. The ability to transform changes in the m agnetic eld into electrical voltage and vice-versa could be used as a m agnetic eld sensor for m agnetic eld m easurem ent, or in electric current m easurem ent.

The remainder of this paper is organized as follows. In section II we sum marize previous calculations on M nO in the usual rocksalt structure, and compare our own results with those of the literature. In Sec. III we describe the electronic structure of M nO in the wurtzite structure. In Sec. IV we present the results of our studies of magneto-structural coupling and piezoelectricity in wurtzite M nO. In the last section we present our conclusions and suggestions for future work.

2 M nO in the Rocksalt structure

The experimental ground state crystal structure of M nO is rocksalt [17]. In this section we present results of our calculations for rocksalt-structure M nO in three magnetic orderings, namely the ferrom agnetic (FM) and two types of anti-ferrom agnetic (AFM) orderings. In type-IAFM ordering (AFI), the M n ions are ferrom agnetically aligned in the [001] planes, with adjacent planes aligned antiferrom agnetically to each other, while in type-II ordering (AFII) they are ferrom agnetically aligned in [111] planes, again with antiferrom agnetic alignment between the planes. The type-II structure is the experimentally observed ground state. The purpose of this section is two-fold. First to compare with existing data in order to verify our methodology and pseudopotentials, and second as a point of comparison for our later studies on M nO in the wurtzite structure.

O ur total energy calculations were carried out using the local spin density approximation (LSDA) to density functional theory (DFT) [18, 19], with pseudopotentials and a planew ave basis as in plemented in the ABIN II [20] computer code. We used the optim ized pseudopotentials developed by Rappe et al., [21] for both the M n and the O atom s. Our sem i-core M n pseudopotential was constructed from a $3s^2$, $3p^6$, $3d^5$ M n²⁺ valence con quration, with cuto radii for the s, p and d states of 12, 11 and 14 a.u.s respectively. Optim ization of the energy cuto was carried out using a wave vector, q_c, of 9 a.u.s. with four Bessel functions. The oxygen pseudopotential used a $2s^2$, $2p^6$ neutral valence conguration with cuto radii of 12 and 1.4 a.u. for s and p states respectively. Optimization of kinetic energy cuto for the oxygen states used $q_c \circ f 7.0$ and $6.5 \circ u \circ w$ ith four and three Bessel functions respectively. Good convergence was obtained with a plane-wave energy cuto of 82 Ry for these pseudopotentials. R hom bohedralm agnetic unit cells, containing two form ula units of M nO, were used for all three magnetic con gurations. Highly converged special k-point sets consisting of 216 points in the rhom bohedral Brillouin zone were used in each case. The exchangecorrelation functional was param eterized using the Perdew-Zunger param eterization [22] of the Ceperley-Alder [23] exchange-correlation functional.

First we optim ized the structures for each magnetic ordering and calculated the total energies, which are listed in Table 1. As expected, we found the AFII con guration to be lowest in energy, with the AFI 0.55 eV /form ula unit higher, and the FM 0.60 eV /form ula unit above AFI. This ordering is consistent with experiment [17], rst-principles Hartree Fock calculations [24] and previous LSDA density functional calculations [25, 26, 27]. Our

M agnetic ordering	Energy (eV / form ula unit)
AFII	0.00
AF1	0.55
FM	0.61

Table 1: Relative energies of di erent magnetic con gurations in rocksalt-structure M nO

optim ized rhom bohedral lattice constant for AFIIM nO was 8.16 a.u., consistent with previous LSDA calculations [28] and showing the typical LSDA underestimation relative to the experimental value of 8.38 a.u. [17].

In Figure 1, we show our calculated band structure of AFIIM nO which is calculated at the experim ental value of 8.38 a.u. (The zero of energy is set to coincide with the highest occupied orbital). The occupied d states lie at the top of the valence band, and their splitting by the rhom bohedral crystal eld into two doublets and a singlet can be seen clearly. Below and slightly separated from them are the predom inantly oxygen p states which have a band width of around 4.5 eV. We will show later that the bandwidths of the Mn and O bands are a ected by both the structure and by the magnetic ordering of the system. We obtain an energy gap of 0.75 eV, in perfect agreem ent with earlier LDA calculations [28]. A nalysis of the orbital character of the LSDA band gap [29] indicates that it lies between predom inantly up-spin d states at the top of the valence band, and down-spin d states on the same Mn at the bottom of the conduction band.

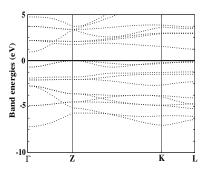


Figure 1: Band structure of AFIIM nO plotted along the high symmetry lines of the rhom - bohedral Brillouin zone.

3 M nO in the wurtzite structure

Having established that our pseudopotentials accurately reproduce previous results for rocksaltstructure M nO, we now turn to the main part of our paper, the study of M nO in the wurtzite structure. As mentioned in the introduction, our motivation is provided by recent experiments in which transition metals are doped into ZnO, where their local environment is the four-fold coordinated structure considered here.

We study the six magnetic orderings of wurtzite M nO shown in Figure 3. (Note that these were previously studied for M nS by H ines et al. [30].) Identical unit cells, containing 8 form ula units, were adopted for all structures, and the pseudopotentials and cut-o swere the same as those described in Section 2. A 4 4 4 k-point grid was used in all the calculations. A two-dimensional projection of the unit cell, looking down the caxis is shown in Figure 3. The lled circles represent one set of ions in the the z=0 and the z=1 planes, while the empty circles show the positions of the other ions in the $z=\frac{1}{2}$ plane.

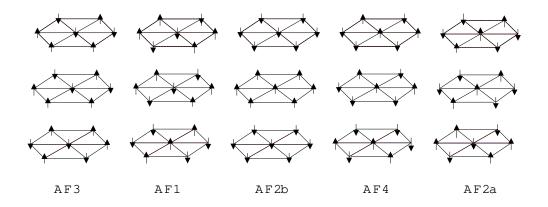


Figure 2: Dierent magnetic orderings for wurtzite structure M nO studied in this work.

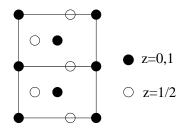


Figure 3: Two-dimensional projection of the unit cell of wurtzite M nO used in this work

4 Energetics

Initially we set the lattice parameters to those of ZnO, and found that the AF3 structure was lowest in energy. However prohibitively large stresses were obtained for all the magnetic orderings at these lattice parameters. Therefore we chose new lattice parameters, a and c of 3.2847 A and 5.1789 A (around 1 % larger than the corresponding values in ZnO) and a u value of 0.3687. These new values gave acceptably small stresses. In order to decouple the e ects of changes in structure from e ects of changes in magnetic ordering, we then calculated the properties of all our magnetic structures at these lattice parameters, and obtained the relative total energies for the wurtzite structures listed in Table 2. The calculated energy ordering is

$$AF3 < AF1 < AF2b < AF4 < AF2a < FM$$
.

Note that the energies of the AF3 and AF1 phases are very similar, as are those of the AF2b, AF4 and AF2a. We relate this below to the ferro-and antiferrom agnetic interactions between M n nearest neighbors. As in the rocksalt case, the ferrom agnetic phase is highest in energy. It is notable that the relative energies per form ula unit of the AF3 wurtzite structure and the AFII rocksalt structure are the same within the errors of the calculations. This suggests that it is not unfavorable to incorporate M n into a tetrahedral environm ent.

In Figure 4 we show the band structures for AF3 and FM wurtzite structure M nO (only the up-spin states are shown in the FM case). Note that in both cases we obtain metallic

M agnetic ordering	Energy (eV / form u la un it)		
AF3	0.000		
AF1	0.002		
AF2b	0.098		
AF4	0.113		
AF2a	0.118		
FM	0.426		

Table 2: Relative energies of the dierent magnetic orderings in wurtzite M nO. The energies are given relative to the reference lowest energy AF3 structure.

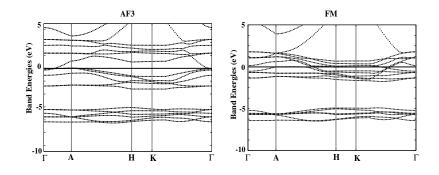


Figure 4: B and structures of wurtzite M nO for AFM (left) and FM (right) orderings, only the up spin states are shown in the FM case.

band structures, with the FM phase having num erous M n d derived bands crossing the Ferm i energy. The AF3 phase (and the other AFM phases, which are not shown) is close to being gapped, with only the M n 4s band crossing the Ferm i energy at the point. We point out that the metallicity is an artifact of the underestimation of the gap by the LSDA, and in practice we anticipate that all of the AFM structures should be insulating. Again the top of the valence band is composed of predom inantly M n 3d states, which this time show the e - t₂ crystal eld splitting of the tetrahedral coordination. The predom inantly oxygen 2p bands are again below the Mn d bands and separated from them by a gap. The bottom of the conduction band is largely composed of M n 3d states, except for the broad 4s band that crosses the Ferm i energy. C om pared with the rocksalt band structure, the bands are narrower, as anticipated for Mn in four-fold rather than six-fold coordination. In addition, it is notable that the wurtzite AFM structure has broader bands than the wurtzite FM. This re ects the increase in hybridization possible, via the usual superexchange interaction, in the AFM bonded con guration. Mn-0 hybridization is unfavorable in the FM con guration between $d^5 M n^{2+}$ ions as a result of H und's rule. Cartoons of the M n-O bonding in the AFM and FM cases are shown in Figure 5.

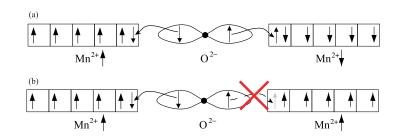


Figure 5: Schematic of (a) favorable M n-O hybridization in the AFM con guration and (b) unfavorable hybridization in the FM con guration. In (a) the M n ions are antiferrom agnetically coupled. Therefore the down-spin oxygen 2p electron undergoes covalent bond form ation with an up-spin M n 3d electron (left) leaving an up-spin oxygen 2p electron to form a covalent bond with a down-spin M n 3d electron (right). In (b) the M n ions are ferrom agnetically coupled. Therefore if the down-spin oxygen 2p electron bonds with an up-spin M n 3d electron on the left (as in the antiferrom agnetically coupled case above) the remaining up-spin oxygen 2p electron is unable to bond with the up-spin M n 3d electrons on the right. Therefore the am ount of hybridization, and hence the band width, is reduced in the ferrom agnetic case.

4.1 Exchange Couplings

To understand the relative energies of the di erent spin orderings, we next analyze the energy di erences between the con gurations using a two-parameter H eisenberg m odel;

$$H = E_0 + J_{ij}S_iS_j$$
(1)

where $S_1 S_j = +1$ if the spins i and j are parallel, and -1 if they are antiparallel. We include two di erent values for J; an in-plane M n-M n interaction, J_p , and an out-of-plane (along c) interaction, J_c , as shown in Figure 6. Note that, for the idealwartzite structure, the in-plane and out-of-plane M n-M n distances are identical, and we would expect to obtain $J_p = J_c$ in the absence of any kind of spin-orbit coupling. However, we constrain the parameter u to be 0.368 which is smaller than the ideal value of 0.375 and hence we nd a percentage di erence in J_p and J_c of the order of the deviation from the ideal value.

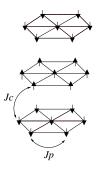


Figure 6: Schem atic of the exchange parameters J_p and J_c .

Table 3 gives the num ber of parallel and antiparallel in-plane and out-of-plane nearest neighbors for a M n ion in each magnetic structure. Note that the AF3 and AF1 structures have

		AF3	AF1	AF2b	FΜ	AF4	AF2a
in-plane	"#	4	4	0	0	4	4
	""	2	2	6	6	2	2
out-of-plane	"#	4	4	6	0	2	2
		2	2	0	6	4	4

Table 3: Number of in-plane and out-ofplane FM and AFM interactions for each magnetic con guration.

identical types of nearest-neighbor (nn) M n-M n interactions (4 in-plane AFM and 4 out-ofplane AFM), which explains their similar energies. Similarly, AF4 and AF2a have identical numbers of nn interactions to each other, but have fewer AFM interactions than AF3 and AF1 (4 in-plane AFM and 2 out-of-plane AFM). AF2b, which is close in energy to AF4 and AF2a has the same total number of nn AFM interactions (six), but they all occur out-of-plane. Finally the FM phase has no AFM interactions, leading to its correspondingly higher energy. By tting the energies of the six con gurations onto the H eisenberg m odel, we obtained the parameters $J_{\rm p}=-0.023$ eV and $J_{\rm c}=-0.028$ eV, with a root mean square deviation of 0.003. The sm all deviation indicates that a nearest-neighbor H eisenberg m odel describes the energetics of the system well, and suggests that m ore distant exchange interactions are weak com pared to the nearest-neighbor interactions. Since the M n-M n in-plane bond length is alm ost equal to the out-of-plane M n-M n bond length, we obtain $J_{\rm p}$ $J_{\rm c}$ as expected.

To conclude this section, we note that AFM coupling ism ore favourable than FM for both in-plane and out-of-plane M n-O -M n bonds and. This suggests that, if doping of M n ions into ZnO results in clustering of the magnetic ions, we will obtain strong antiferrom agnetism.

4.2 Forces and stresses

In m any m agnetic com pounds, a change of m agnetic ordering causes a stress which induces a structural distortion β 1]. For example, in rocksalt M nO, AFM spin ordering causes a reduction in m agnetic symmetry from cubic to rhom bohedral, which is accompanied by a structural transition [32]. In some m aterials, in which there is strong m agneto-structural coupling, the distortion can be quite large. For example in CrN the m agnetic ordering induces a transition from cubic to orthorhom bic symmetry [31, 33, 34]. And in LaM nO₃ the observed A -type antiferrom agnetic ordering is unstable in the presence of distortions [35]. The concept of m agnetic stress has been introduced to describe structural phase transitions that are induced by m agnetic ordering [31]. In this section we investigate the m agnetostructural coupling in wurtzite M nO, as a precursor to studying the piezoelectric properties in the next Section.

K exping the lattice parameters of all the structures xed at the AF3 values, the spin ordering was changed to each of the other ve con gurations in turn, and the electronic structure was obtained and the stresses and the forces for each magnetic phase were calculated. In the table below, the relative stresses on the unit cell along the z direction and largest forces on the M n atom s are tabulated for each magnetic ordering.

	AI	F 3	AI	71	AB	'2b	AI	F 4	AF	'2a
Stress ₃₃ (Ha/bohr ³)	-7.35	10 ⁵	-7.067	10 ⁵	8.35	10 ⁵	-2.39	10 4	-2.46	10 4
Force(max) (Ha/bohr)	5 : 87	10 ¹	5.76	10 ¹	4.42	10 ³	8.43	10 ¹	8,24	10 ¹

W e observe sim ilar groupings as those obtained for the relative energies. The AF1 and AF3

phases are similar in the spin-environment and therefore have similar stresses and forces for the same structure. Likewise, the AF2a and AF4 spin orderings show similar stresses and forces to each other, but both are considerably larger than those in the AF3 and AF1 structures. The signi cant change in the stress when the magnetic ordering is changed indicates a strong coupling between the magnetic moments of the atom s and the crystal structure.

5 Piezoelectricity

The piezoelectric constant relates the stress response of a material to a uniform electric eld or conversely the macroscopic polarization induced by a a macroscopic strain. The latter de nition is used here to calculate the electro-mechanical response from mst principles. We calculated the changes in macroscopic polarization using the Berry phase approach [36] within the ABINIT density functional program [20]. First, the equilibrium structure parameters (a_0 , c_0 and u_0) were obtained for each magnetic con guration, in turn and the spontaneous polarizations, P_0 , (along the z-axis) were calculated. Then the reference structure was strained along the z axis by 1 % ($e_{zz} = 0.01$, e_{zz} is the percentage change in strain along the z-axis) and its structure relaxed with respect to the internal strain (structural parameter u). The polarization P_1 for the relaxed structure was then calculated, and the piezoelectric co-e cient e a_{33} was obtained using its de nition:

$$e_{33} = \frac{(P_1 P_0)}{e_{zz}}$$
 (2)

Subsequent application of a -1% strain along the z-axis showed that the polarization deviated slightly from linearity in M nO (in contrast to ZnO, where it is strictly linear over that range with the same set of convergence parameters.) All the Berry phase polarization calculations used a 2 2 8 k-point mesh and a wavefunction tolerance set to 10¹⁵. Calculations for one of the con gurations were repeated with a 3 3 8 mesh to test convergence. A 2 2 mesh in the ab-plane is found to be su cient as it corresponds to a 4 4 mesh for the primitive unit cell of the wurtzite structure. In order to avoid the point, where the gap vanishes indicating metallicity, the k-point grid was shifted by $\frac{1}{2}$ along the three co-ordinate axes.

O ur calculated values of e_{33} for all the ve m agnetic orderings are listed in Table 3. W hile we nd groupings of con gurations (AF3 and AF1), (AF4 and AF2a) such that the energies and stresses are sim ilar for m embers of a given group, their piezoelectric constants are found to be som ewhat dissim ilar, as they are second order derivatives of energy.

The piezoelectric constant of wurtzite M nO in the lowest energy AF3 con guration is about 3 times larger than that of ZnO (1:0 $1.2C = m^2$ [3]). In ZnO, the phonon (internal strain) contribution to the piezoelectric constant was found to dom inate and this was attributed partly to hybridization between the led 3d band of Zn and the 2p band of oxygen. In AF3 M nO, we nd that the electronic contribution to e_{33} is also signi cant and in fact has the same sign as that of the phonon contribution (in contrast with ZnO, where the two contributions partially compensate). The large electronic contribution arises because the d band of M n is only partially occupied and can therefore contribute directly to the piezoelectric response through change in its electron content.

Note that the enhanced piezoelectric response which we nd in wurtzite M nO is consistent with earlier observations of large dielectric and piezoelectric constants in systems that are close to electronic and structural instabilities [37]. W urtzite structure M nO is both unstable structurally (with the rocksalt structure being the grounds state) and has other m agnetic con gurations close in energy. Finally we point out that M n doped ZnO should have a strong piezoelectric response provided that it rem ains insulating.

0 rdering	AF3	AF1	AF2b	AF4	AF2a
e_{33} (C /m 2)	4.81	11,24	0.911	2.05	1.30
P ₀ (C/m ²)	0.045	0.053	0.017	0.014	-0.072

Table 4: Piezoelectric constant, e_{33} and the spontaneous polarization, P_0 , (C =m²) for the di erent m agnetic orderings of wurtzite M nO.

6 Summary and Conclusions

In this research we investigated the electronic properties of wurtzite M nO using density functional calculations. Using Berry phase polarization calculations we found that m agnetic M nO is a stronger piezoelectric than non-m agnetic ZnO. This to our know ledge is the rst calculation of piezoelectric response in a magnetic material and shows clearly that presence of magnetism does not preclude a piezoelectric response and can even enhance it. The reason for the enhancement is that, in addition to the phonon contribution found in ZnO, the electrons in the partially led d band of M n also contribute to the piezoelectricity. Our results suggest that piezoelectricity should persist in M n doped ZnO provided that it remains insulating. O n analyzing the energetics of the di erent magnetic orderings for wurtzite M nO, how ever we nd that anti-ferrom agnetic ordering is more stable than ferrom agnetic ordering with the most stable structure having the largest number of nearest neighbor antiferrom agnetic interactions. From this we can conclude that if doping of M n in ZnO results in clustering, ferrom agnetism is unlikely.

7 A cknow ledgem ents

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